## **Vishay Semiconductors**





SMA (DO-214AC)

### LINKS TO ADDITIONAL RESOURCES

3D Models

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	1 A			
V <sub>R</sub>	1200 V			
V <sub>F</sub> at I <sub>F</sub>	1.10 V			
t <sub>rr</sub>	75 ns			
T <sub>J</sub> max.	175 °C			
Package	SMA (DO-214AC)			
Circuit configuration	Single			

### **FEATURES**

- Hyperfast recovery time, reduced  $\mathsf{Q}_{\mathrm{rr}},$  and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use as clamp, snubber and freewheeling diode in a flyback aux power supplies, bootstrap and desaturate for HV MOSFET and IGBT driver, high frequency rectifiers in a cuk and sepic circuit for LED lighting.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

#### MECHANICAL DATA

Case: SMA (DO-214AC)

Molding compound meets UL 94 V-0 flammability rating

**Terminals:** matte tin plated leads, solderable per J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V <sub>RRM</sub>		1200	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>Sp</sub> = 144 °C, D = 0.5	1	^		
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_J = 25$ °C, 8.3 ms sine pulse	21	A		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	1200	-	-		
		I <sub>F</sub> = 1 A	-	1.35	1.80	v	
Forward voltage, per diode	V <sub>F</sub>	I <sub>F</sub> = 1 A, T <sub>J</sub> = 125 °C	-	1.17	1.55		
		I <sub>F</sub> = 1 A, T <sub>J</sub> = 150 °C	-	1.10	1.44		
Reverse leakage current, per diode	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	5		
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	50	μA	
Junction capacitance	CT	V <sub>R</sub> = 1200 V	-	3.5	-	pF	

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RoHS

COMPLIANT

HALOGEN

FREE





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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A			75	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	99	-	ns A nC
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 1 A, dI <sub>F</sub> /dt = 200 A/μs, V <sub>B</sub> = 800 V	-	137	-	
Pools recovery ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	3.5	-	
Peak recovery current		T <sub>J</sub> = 125 °C		-	4.5	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	150	-	
		T <sub>J</sub> = 125 °C		-	286	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C	
Thermal resistance, junction to mount	R <sub>thJM</sub> <sup>(1)</sup>	Device mounted on PCB with 2 x 3.5 mm soldering lands	-	15	18	°C/W	
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Device mounted on PCB with recommended pad size	-	110	-	°C/W	
Approximate weight				0.07		g	
Marking device		Case style SMA (DO-214AC)		11	112		

### Note

<sup>(1)</sup> Thermal resistance junction to mount follows JEDEC<sup>®</sup> 51-14 transient dual interface test method (TDIM)

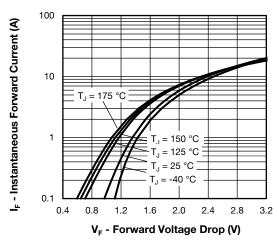


Fig. 1 - Typical Forward Voltage Drop Characteristics

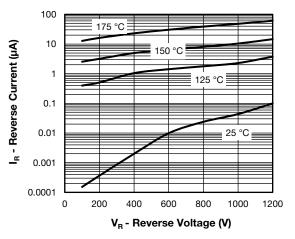


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



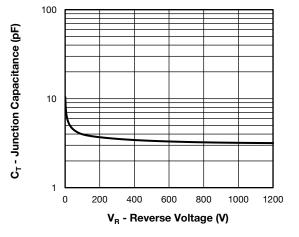


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

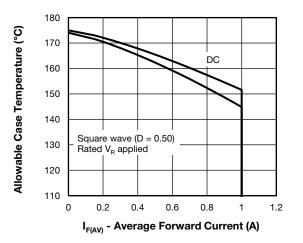


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

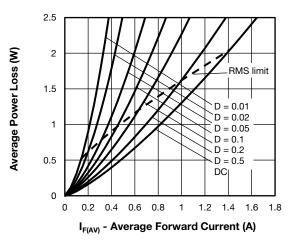


Fig. 5 - Forward Power Loss Characteristics

#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- $\begin{array}{l} \mbox{Pd} = \mbox{forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/\mbox{D}) \mbox{ (see fig. 5);} \\ \mbox{Pd}_{REV} = \mbox{inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = \mbox{rated} \mbox{V}_{R1} \end{array}$

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VS-E7MH0112HM3

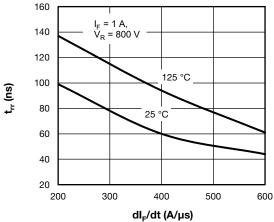


Fig. 6 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

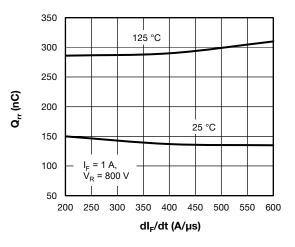


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

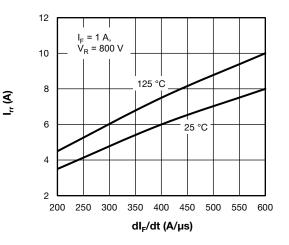


Fig. 8 - I<sub>rr</sub> (A) vs. dI<sub>F</sub>/dt

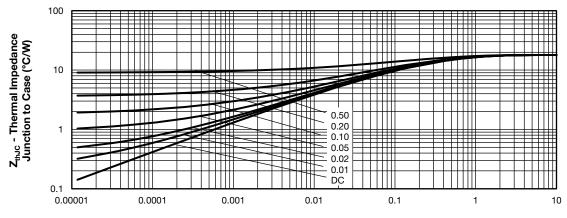
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# **VS-E7MH0112HM3**

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t<sub>1</sub> - Rectangular Pulse Duration (s)

Fig. 9 - Transient Thermal Impedance, Junction to Case

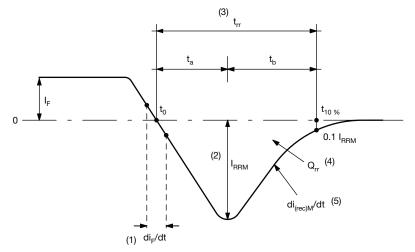


Fig. 10 - Reverse Recovery Waveform and Definitions

#### Notes

(1) di<sub>F</sub>/dt - rate of change of current through zero crossing

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- <sup>(2)</sup> I<sub>RRM</sub> peak reverse recovery current
- $^{(3)}$  t<sub>rr</sub> reverse recovery time measured from t<sub>0</sub>, crossing point of negative going I<sub>F</sub>, to point t<sub>10%</sub>, 0.1 I<sub>RRM</sub>
- $^{(4)}$   $Q_{rr}$  area under curve defined by  $t_0$  and  $t_{10}\ _{\%}$

$$Q_{rr} = \int_{0}^{t_{10\%}} I(t) dt$$

 $^{(5)}$  di<sub>(rec)</sub>M/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

## Vishay Semiconductors



### **ORDERING INFORMATION TABLE**

Device code	VS-	E	7	м	н	01	12	Н	М3
		2	3	4	5	6	7	8	9
	1	- Visl	nay Sen	niconduc	ctors pro	oduct			
	2		cuit conf single c	iguration diode	า:				
	3.	- 7 =	FRED g	generatio	on 7				
	4	- M =	SMA p	ackage					
	5		cess typ hyperfa	oe, ist recov	very				
	6	- Cur	rent rati	ng (01 =	= 1 A)				
	7	- Vol	tage coo	de (12 =	1200 V	)			
	8	- н=	AEC-Q	101 qua	lified				
	9	- M3	= halog	en-free,	RoHS-0	complia	nt, and	termina	tions lea

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRI						
VS-E7MH0112HM3/I	7500	7500	13"diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95400				
Part marking information	www.vishay.com/doc?95472				
Packaging information	www.vishay.com/doc?95404				
SPICE model	www.vishay.com/doc?97060				



## **Outline Dimensions**

## **Vishay Semiconductors**

SMA

### **DIMENSIONS** in inches (millimeters)

DO-214AC (SMA)





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